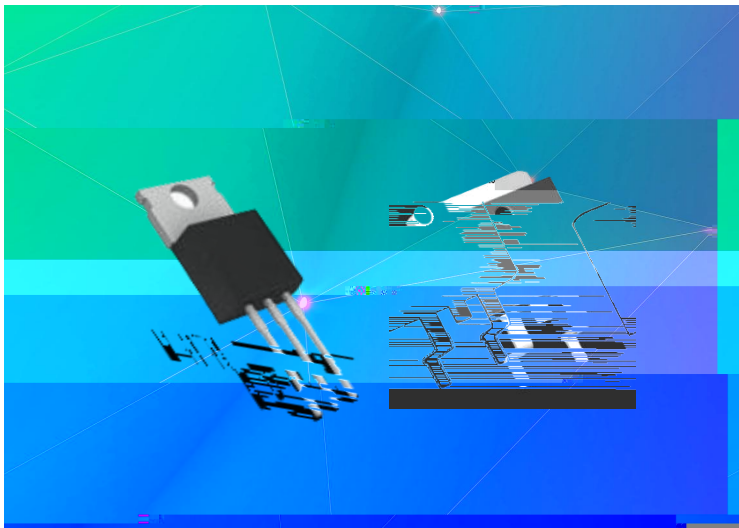


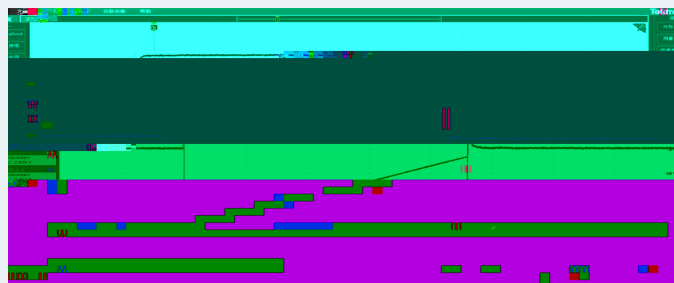
微沟



650V IGBT

TO-220/TO-263

1. 650V 50A @ $T_c = 100$
3. I_{cm} 300A
- 4.



Product Name	V_{CES} (V)	I_c (A)	$V_{GE(th)}$ (V)	V_{GE} (V)	P_d (W)	T_j
DGP50N65ATS2A	650V	50A	4.8		283	-40~175
DGB50N65ATS2A	650V	50A	4.8		283	-40~175



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,fa sa

1. Micro-trench process platform, a highly cost-effective solution for high performance

New Product Announcement